High Performance Regulators for PCs

Nch FET Ultra LDO Controllers for PC Chipsets

BD3504FVM,BD3500FVM,BD3501FVM,BD3502FVM

No.10030EAT29

●Description

The BD3500/01/02/04FVM is an ultra-low dropout linear regulator controller for chipset that can achieve ultra-low voltage input to ultra-low voltage output. By using N-MOSFET for external power transistor, the controller can be used at ultra-low I/O voltage difference up to voltage difference generated by ON resistance. In addition, because best suited power transistor can be chosen in accord with the output current, downsizing and cost reduction of the set can be achieved. Because by reducing the I/O voltage difference, large current output is achieved and conversion loss can be reduced, switching power supply can be replaced. BD3500/01/02/04FVM does not need any choke coil, diode for rectification and power transistor which are required for switching power supply, total cost of the set can be reduced and compact size can be achieved for the set. Using external resistors, optional output from 0.65V to 2.5V can be set. In addition, since voltage output start-up time can be adjusted by using the NRCS terminal, it is possible to flexibly meet the power supply sequence of the set.

●Features

1) Reduced rush current by NRCS
2) Built-in driver for external Nch h transistor
3) Adoption of MSOP8 package: 2.9 x 4.0 x 0.9 (mm)
4) Built-in timer latch short protection circuit
5) Built-in low input maloperation prevention circuit
6) Output voltage variable type
7) Built-in overheat protection circuit

●Applications

Mobile PC, desktop PC, digital home appliances

●Line up matrix

Parameter	BD3500FVM	BD3501FVM	BD3502FVM	BD3504FVM
Output Voltage	1.8V (Fix)	1.5V (Fix)	1.2V (Fix)	Variable(0.65～2.5V)
NRCS (Soft start)	○ (Independent Setting)	○ (Independent Setting)	○ (Independent Setting)	○ (Same Timer Latch)
Timer latch short protection circuit	○ (Independent Setting)	○ (Independent Setting)	○ (Independent Setting)	○ (Same NRCS)
V_{IN} UVLO	Hysterisis	Hysterisis	Hysterisis	Detected at start-up only (set by external resistor)
External FET GATE Drive Current	+1/-3mA	+1/-3mA	+1/-3mA	+3/-3mA

● **Absolute maximum ratings (Ta=25℃)**

◎BD3500/01/02FVM

Parameter	Symbol	Ratings	Unit
Input Voltage	VCC	7 [*1]	V
Drain Voltage (VIN)	VIN	7	V
Enable Input Voltage	Ven	7	V
Power Dissipation	Pd	437.5 [*2]	mW
Operating Temperature Range	Topr	-10～+100	℃
Storage Temperature Range	Tstg	-55～+150	℃
Maximum Junction Temperature	Tjmax	+150	℃

*1 However, not exceeding Pd.
*2 Pd derating at 3.5mW/℃ for temperature above Ta=25℃

◎BD3504FVM

Parameter	Symbol	Ratings	Unit
Supply Voltage	VCC	7 [*3]	V
Drain Voltage	VD	7	V
Enable Input Voltage	Ven	7	V
Power dissipation	Pd	437.5 [*4]	mW
Operating temperature range	Topr	-10～+100	℃
Storage temperature range	Tstg	-55～+150	℃
Maximum Junction Temperature	Tjmax	+150	℃

*3 However, not exceeding Pd.
*4 Pd derating at 3.5mW/℃ for temperature above Ta=25℃

● **Recommended operating conditions**

◎BD3500/01/02FVM

Parameter	Symbol	Ratings		Unit
		MIN	MAX	
Supply Voltage	VCC	4.5	5.5	V
Drain Voltage(VIN)	VIN	Vo×1.15	5.5	V
Enable Input Voltage	Ven	-0.3	5.5	V
Capacitor on NRCS Terminal	CNRCS	0.001	1	µF
Capacitor on SCP Terminal	CSCP	0.001	1	µF

★ No radiation-resistant design is adopted for the present product.

◎BD3504FVM

Parameter	Symbol	Ratings		Unit
		MIN	MAX	
Supply Voltage	VCC	4.5	5.5	V
Drain Voltage	VD	0.65	5.5	V
Enable Input Voltage	Ven	-0.3	5.5	V
Capacitor in NRCS pin	CNRCS	0.001	1	µF
Output Voltage	VOUT	0.65	2.5	V

★ No radiation-resistant design is adopted for the present product.

●**Electrical characteristics (unless otherwise noted, Ta=25℃ VCC=5V Vin=3.3V Ven=3V)**

◎BD3500FVM/BD3501FVM/BD3502FVM

Parameter	Symbol	Standard Value			Unit	Condition
		MIN	TYP	MAX		
Bias Current	ICC	-	0.8	1.6	mA	
Shut Down Mode Current	IST	-	0	10	µA	Ven=0V
Output Voltage 1 (BD3500FVM)	Vo1	1.782	1.800	1.818	V	Io=50mA
Output Voltage 1 (BD3501FVM)	Vo1	1.485	1.500	1.515	V	Io=50mA
Output Voltage 1 (BD3502FVM)	Vo1	1.188	1.200	1.212	V	Io=50mA
Output Voltage 2 (BD3500FVM)	Vo2	1.746	1.800	1.854	V	Vcc=4.5V to 5.5V ,Io=0 to 3A Ta=-10℃ to 100℃(※)
Output Voltage 2 (BD3501FVM)	Vo2	1.455	1.500	1.545	V	Vcc=4.5V to 5.5V ,Io=0 to 3A Ta=-10℃ to 100℃(※)
Output Voltage 2 (BD3502FVM)	Vo2	1.164	1.200	1.236	V	Vcc=4.5V to 5.5V ,Io=0 to 3A Ta=-10℃ to 100℃(※)
Line Regulation	Reg.l	-	0.1	0.5	%/V	VCC=4.5V to 5.5V
Load Regulation	Reg.L	-	0.5	10	mV	Io=0 to 3A
[Enable]						
High Level Enable Input Voltage	Enhi	2	-	Vcc	V	
Low Level Enable Input Voltage	Enlow	-0.3	-	0.8	V	
Enable Pin Input Current	Ien	-	7	10	µA	Ven=3V
[NRCS]						
NRCS Charge Current	Inrcs	14	20	26	µA	Vnrcs=0.5V,VCC=4.5V to 5.5V Ta=-10℃ to 100℃ (※)
NRCS Standby Voltage	Vnrcs	-	0	50	mV	Ven=0V
[Voltage Feed Back]						
VFB Input Bias Current	IFB	-	0.7	1.2	mA	Ven=3V
VFB Standby Current	FBSTB	150	-	-	mA	Ven=0V,VFB=1V
[Output MOSFET Driver]						
MOSFET Driver Source Current	IGSO	0.5	1	1.5	mA	VFB=Vo-0.1V,G=Vo+1V
MOSFET Driver Sink Current	IGSI	2	3	4	mA	VFB=Vo+0.1V,G=Vo+1V
[UVLO]						
VCC UVLO	VccUVLO	4.2	4.35	4.5	V	Vcc:Sweep up
VCC UVLO Hysteresis	Vcchys	100	160	220	mV	Vcc:Sweep down
VIN UVLO	VINUVLO	Vo×1.05	Vo×1.1	Vo×1.15	V	VIN:Sweep up
VIN UVLO Hysteresis	VINhys	100	160	220	mV	VIN:Sweep down
[SCP]						
SCP Charge Current	Iscpch	14	20	26	µA	VSCP=0.5V,VCC=4.5V to 5.5V Ta=-10℃ to 100℃ (※)
SCP Discharge Current	IscpDi	0.5	-	-	mA	VSCP=0.5V
SCP Threshold Voltage	Vscpth	1.2	1.3	1.4	V	
Short Detect Voltage	Vscp	Vo×0.6	Vo×0.7	Vo×0.8	V	
SCP Stand-by Voltage	VSTB	-	0	50	mV	

(※) Design Guarantee

●**Electrical characteristics (unless otherwise noted, Ta=25℃ VCC=5V VIN=3.3V Ven=3V. R1=R1'=∞Ω, R2=R2'=0Ω)**
　　◎BD3504FVM

| Parameter	Symbol	Standard Value			Unit	Condition
		MIN	TYP	MAX		
Bias Current	ICC	-	0.85	1.7	mA	
Shut Down Mode Current	IST	-	0	10	µA	Ven=0V
Feed Back Voltage 1	VFB1	0.643	0.650	0.657	V	Io=50mA
Feed Back Voltage 2	VFB2	0.630	0.650	0.670	V	Vcc=4.5V to 5.5V , Ta=-10℃ to 100℃(※)
Output Voltage	Vo	-	1.20	-	V	R1=R1'=3.9kΩ, R2=R2'=3.3KΩ
Line Regulation	Reg.l	-	0.1	0.5	%/V	VCC=4.5V to 5.5V
Load Regulation	Reg.L	-	0.5	10	mV	Io=0 to 3A
[Enable]						
High Level Enable Input Voltage	Enhi	2	-	Vcc	V	
Low Level Enable Input Voltage	Enlow	-0.3	-	0.8	V	
Enable pin Input Current	Ien	-	7	10	µA	Ven=3V
[Voltage Feed Back]						
VFB Input Bias Current	IFB	-	80	-	nA	
[Source Voltage]						
VS Input Bias Current	ISBIAS	-	1.2	2.4	mA	
VS Standby Current	ISSTB	150	-	-	mA	VS=1V Ven=0V
[Output MOSFET Driver]						
MOSFET Driver Source Current	IGSO	2	3	4	mA	VFB=0.6V,VGATE=2.5V
MOSFET Driver Sink Current	IGSI	2	3	4	mA	VFB=0.7V,VGATE=2.5V
[UVLO]						
VCC UVLO	VccUVLO	4.20	4.35	4.50	V	Vcc:Sweep up
VCC UVLO Hysterisis	Vcchys	100	160	220	mV	Vcc:Sweep down
VD UVLO	VDUVLO	Vo×0.6	Vo×0.7	Vo×0.8	V	VD:Sweep up
[Drain Voltage Sensing]						
VD Input bias Current	Ivd	-	0	-	nA	
[NRCS/SCP]						
NRCS Charge Current	Inrcs	14	20	26	µA	VNRCS=0.5V
SCP Charge Current	Iscpch	14	20	26	µA	VNRCS=0.5V
SCP Discharge Current	IscpDi	0.3	-	-	mA	VNRCS=0.5V
SCP Threshold Voltage	Vscp	1.2	1.3	1.4	V	
Short Detect Voltage	Voscp	Vo×0.3	Vo×0.35	Vo×0.4	V	
NRCS Stand-by Voltage	VSTB	-	-	50	mV	

(※) Design Guarantee

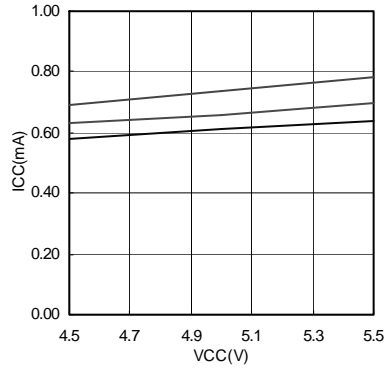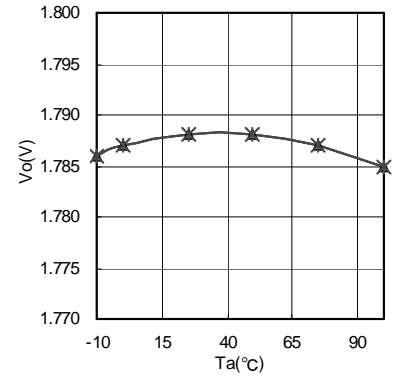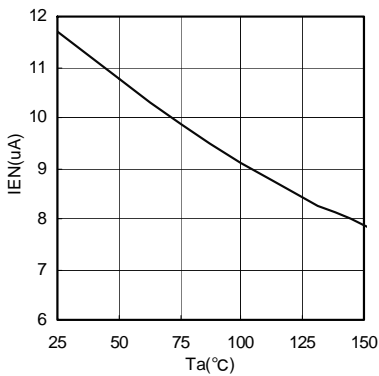● **Reference Data**
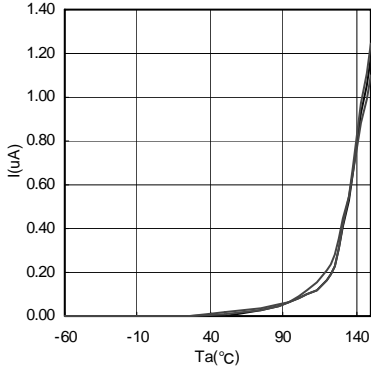
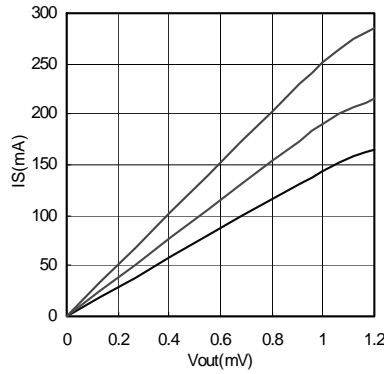Fig.1 Ta-I$_{STB}$

Fig.2 ICC-VCC

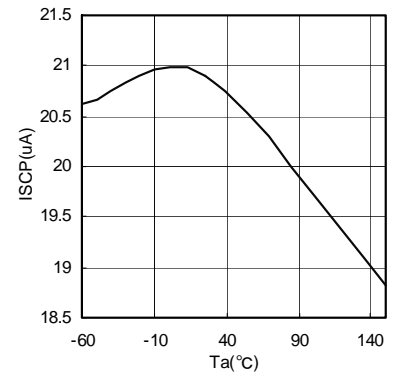Fig.3 Ta-Vo

Fig.4 Ta-I$_{EN}$

Fig.5 VS Discharge Current

Fig.6 Ta-I$_{SCP}$
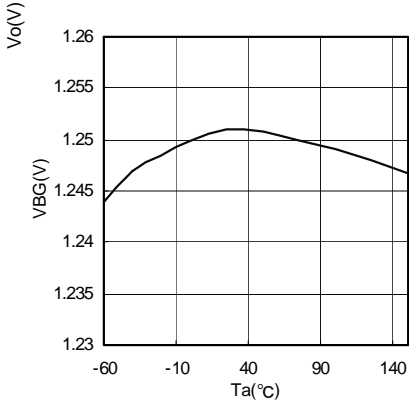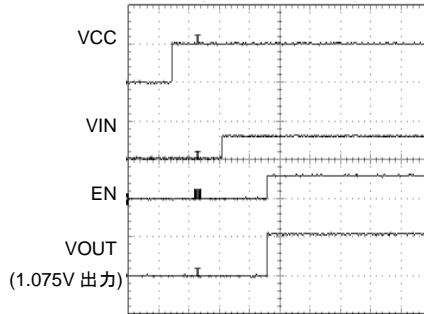

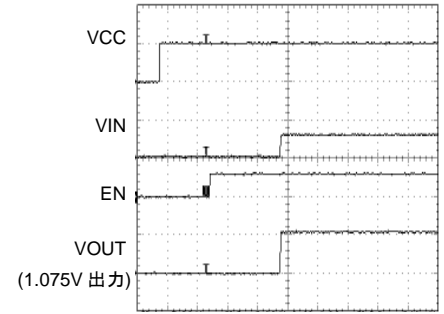Fig.7 Ta-Vo

Fig.8 Input Sequence 1
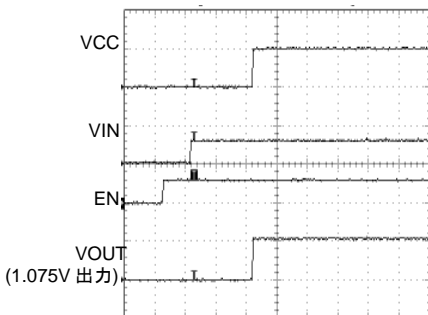EN

Fig 9. Input Sequence 2
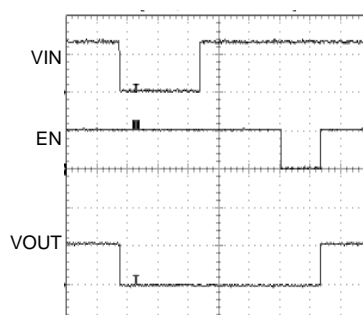VIN

Fig.10 Input Sequence 3
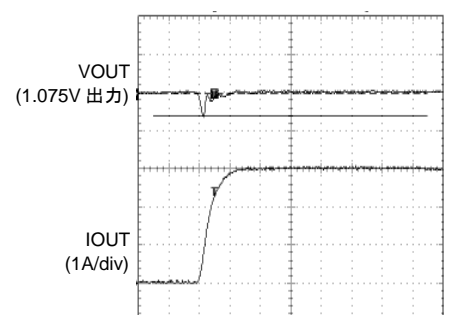Vcc

Fig.11 Input Sequence 4
(Only BD3504FVM)

Fig.12 Transient Response
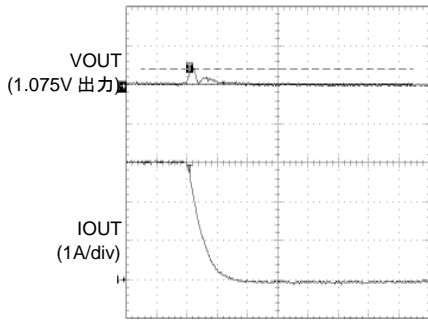0→3A(0.6A/μs) △V=30mV

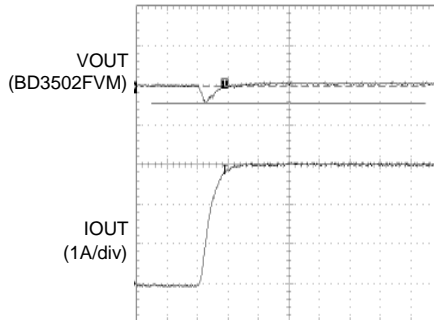Fig.13 Transient Response
3→0A(0.6A/μs) ΔV=20mV

Fig.14 Transient Response
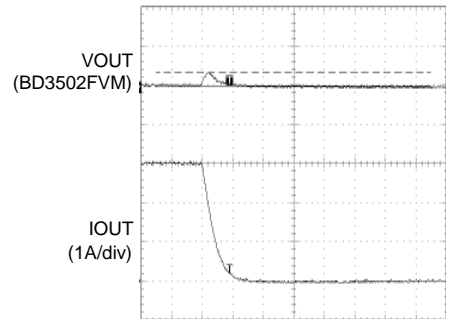0→3A(0.6A/μs) ΔV=21mV

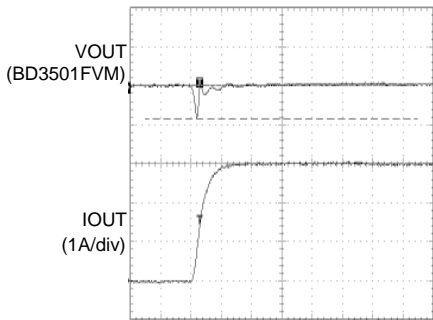Fig.15 Transient Response
3→0A(0.6A/μs) ΔV=17mV

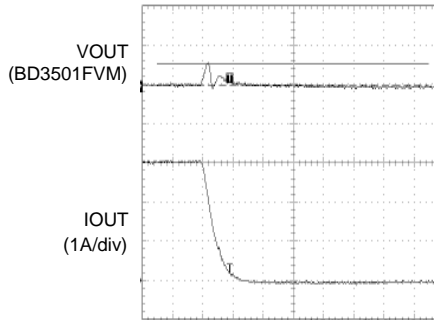Fig.16 Transient Response
0→3A(0.6A/μs) ΔV=42mV

Fig.17 Transient Response
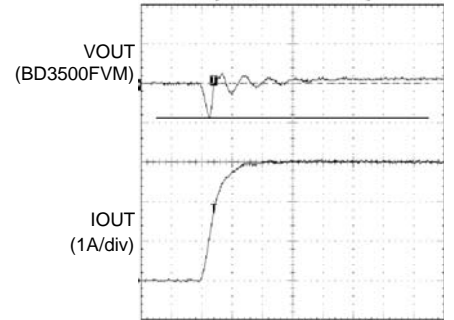3→0A(0.6A/μs) ΔV=27mV

Fig.18 Transient Response
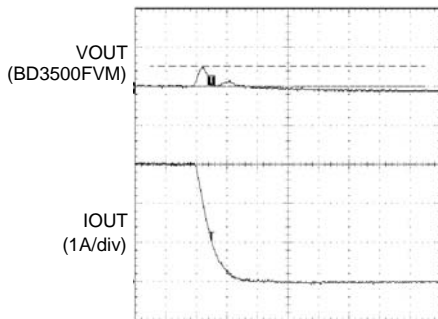0→3A(0.6A/μs) ΔV=44mV

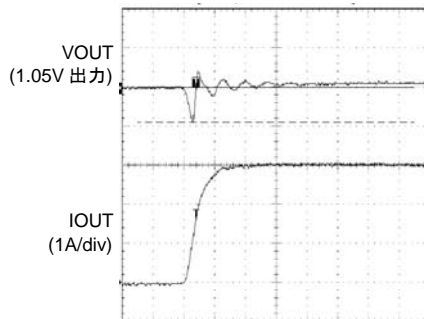Fig.19 Transient Response
3→0A(0.6A/μs) ΔV=26mV

Fig.20 Transient Response
0→3A(0.6A/μs) ΔV=44mV
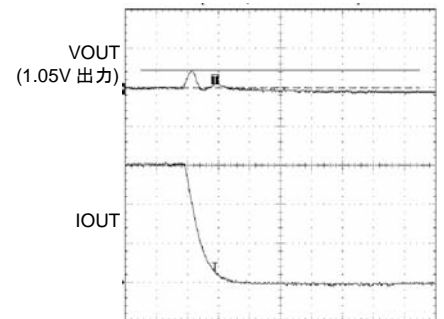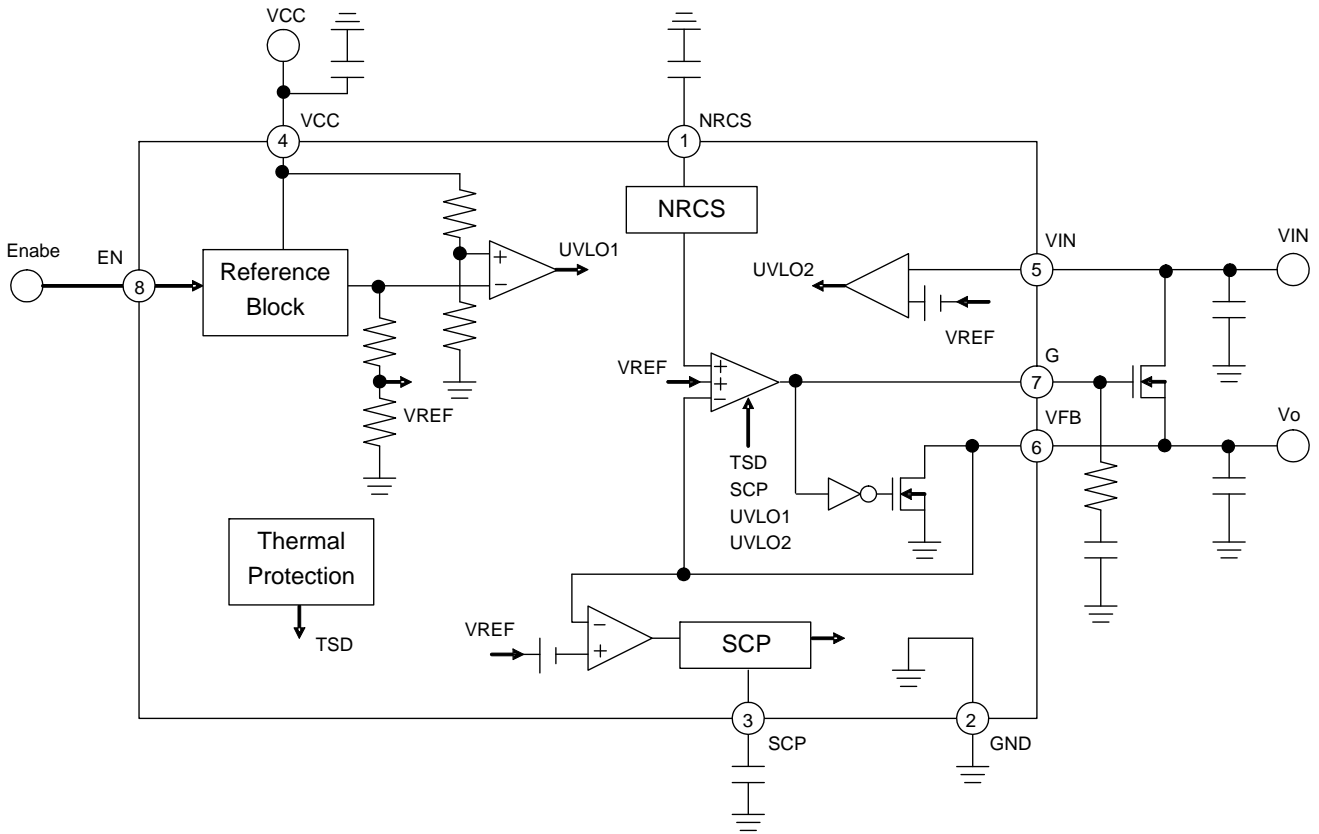

Fig.21 Transient Response
3→0A(0.6A/μs) ΔV=23mV

● **Block Diagram**

◎BD3500FVM/BD3501FVM/BD3502FVM

◎BD3504FVM
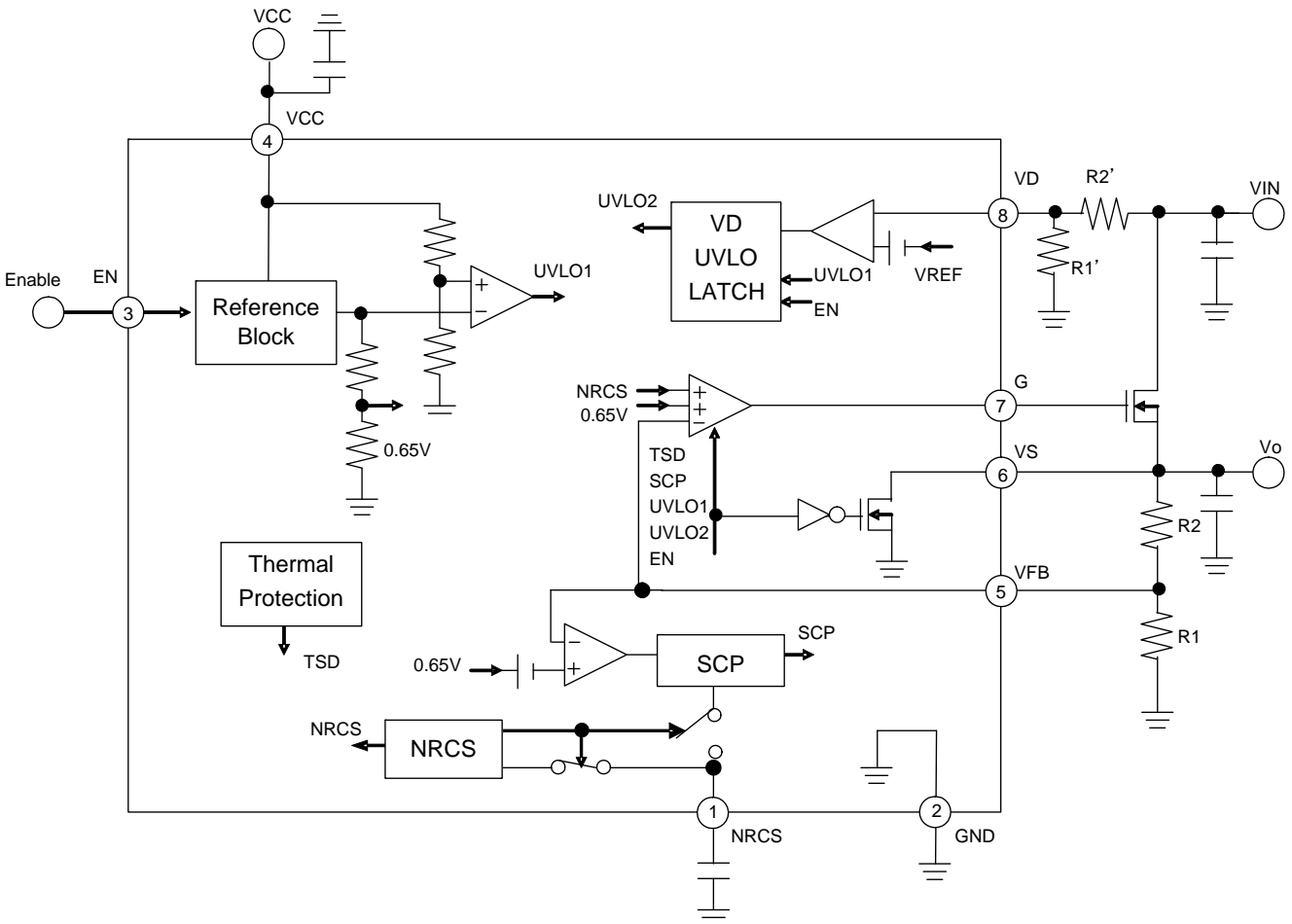
●**Pin Configration and Pin Function**

◎BD3500FVM/BD3501FVM/BD3502FVM

○Pin Configration

NRCS	1		8	EN
GND	2		7	G
SCP	3		6	VFB
VCC	4		5	VIN
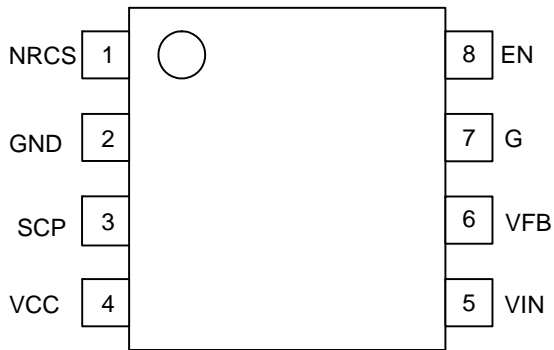
○Pin Function

Pin No.	Pin Name	PIN FUNCTION
1	NRCS	(Non Rush Current on Start up) time setup
2	GND	Ground pin
3	SCP	Timer latch setup for Short Circuit Protection
4	VCC	Power Source
5	VIN	Drain Voltage Sense
6	VFB	Output Voltage Feedback
7	G	MOSFET Driver Output
8	EN	Enable

◎BD3504FVM

○Pin Configration

NRCS	1		8	VD
GND	2		7	G
EN	3		6	VS
VCC	4		5	VFB
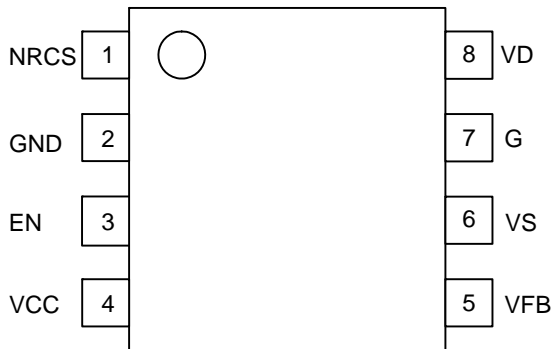
○Pin Function

Pin No.	Pin Name	PIN FUNCTION
1	NRCS	NRCS (Non Rush Current on Start up) time setup. Timer latch setup for Short Circuit Protection operating time set up Pin.
2	GND	Ground Pin
3	EN	Enable Pin
4	VCC	Power Source
5	VFB	Output Voltage Feedback
6	VS	Source Voltage Pin
7	G	MOSFET Driver Output
8	VD	Drain Voltage Sense

●**Pin Function Descriptions**

・VCC

BD3500/01/02/04FVM has an independent power input pin for an internal circuit operation of IC.   This is used for bias of IC internal circuit and external N-MOSFET.   The voltage used of VCC terminal is 5.0V and maximum current is 1.7 mA. It is recommended to connect a bypass capacitor of 0.1 μF or so to VCC pin.

・EN

With an input of 2.0 volts or higher, the EN terminal turns to "High" level and VOUT is outputted.   At 0.8V or lower, it detects "Low" level and VOUT is turned OFF and simultaneously, the discharge circuit inside the VS terminal is activated and lowers output voltage (150 mA (Min) when VFB//VS=1V and VEN=0V).

・VIN(BD3500/01/02FVM)

The VIN terminal is a drain voltage detection terminal of external N-MOSFET.   In the event that the VIN terminal is lower than 1.1 times the output set voltage, output is turned OFF to prevent low-input maloperation.

・VD(BD3504FVM only)

The VD terminal is a drain voltage detection terminal of external N-MOSFET.   In the event that drain voltage (VIN) is low, output voltage is turned OFF to prevent low-input maloperation.   The reset voltage (VDUVLO) of drain voltage low-input maloperation prevention circuit is determined by the following equation:

$$VDUVLO = VFB \times 0.7 \times \left(\frac{R1'+R2}{R1'} \right)$$

In the event that the maloperation prevention set resistance at the time of low-input drain voltage is set to a resistance value same as output voltage set resistor (R1 = R1', R2 = R2'), low-input maloperation prevention (UVLO) is reset when drain voltage (VIN) reaches 70% of the output voltage.   UVLO detects only at the startup of the EN terminal.

・VFB(BD3504FVM only)

The VFB terminal is a terminal to decide output voltage and is determined by the following equation:

$$VOUT = VFB \times \left(\frac{R1'+R2}{R1'} \right)$$

VFB is controlled to achieve 0.65 V (typ.).

・NRCS terminal

he NRCS terminal is a constant current output terminal, and operates as
- Soft-Start   ...   during start-up
- SCP-Delay   ... after start-up (BD3504FVM only).

How to set Soft-Start of NRCS terminal

The output voltage startup time (TNRCS) is determined by the time when the NRCS terminal reaches VFB (0.65V). During start-up, the NRCS terminal serves as a constant current source (INRCS) of 20 μA (Typ.) output, and charges capacitor (CNRCS) externally connected.   By changing over to internal reference voltage (0.65V) when the NRCS terminal reaches 0.65V, output voltage (VOUT) is fixed.

How to set NRCS terminal short protection Delay (BD3504FVM only)

BD3504FVM has short protection (SCP) activated when output voltage becomes VOUT x 0.35 (typ.) or lower.   The time when short protection is activated until latching takes place (TSCP) is determined by the following equation:

Tscp = CNRCS × Voscp ÷ Iscp

When short protection is activated, the NRCS terminal provides 20 μA (typ.) constant current output (Iscp), and charges the capacitor (CNRCS) externally connected.   When the NRCS terminal reaches 1.3V (Voscp), latch operation is carried out and output voltage is turned OFF.

・SCP(BD3500/01/02FVM)

BD3500/01/02FVM has short protection (SCP) activated when output becomes 70% or lower than the set voltage.   The time when short protection is activated until latching takes place (T_{SCP}) is determined by the following equation:

Tscp = CNRCS × Voscp ÷ Iscp

When short protection is activated, the NRCS terminal provides 20 μA (typ.) constant current output (Iscp), and charges the capacitor (CNRCS) externally connected.   When the NRCS terminal reaches 1.3V (Voscp), latch operation is carried out and output voltage is turned OFF.

・VFB//VS (BD3500FVM/BD3501FVM/BD3502FVM//BD3504FVM)

VFB//VS terminal is a source voltage detection terminal of external N-MOSFET. VFB//VS terminal has the internal discharge circuit activated to lower output voltage when EN becomes a Low level or various protection circuits (TSD, SCP, UVLO) are activated.

・G

G terminal is a gate drive terminal of external N-MOSFET.   Because the output voltage range of G terminal is up to 5V (VCC), it is necessary to use N-MOSFET whose threshold is lower than "5V-VOUT."   In addition, by incorporating a RC snubber circuit to the G terminal, phase allowance of loop gain can be increased and the terminal can accommodate ceramic capacitors.

●**Application circuit**
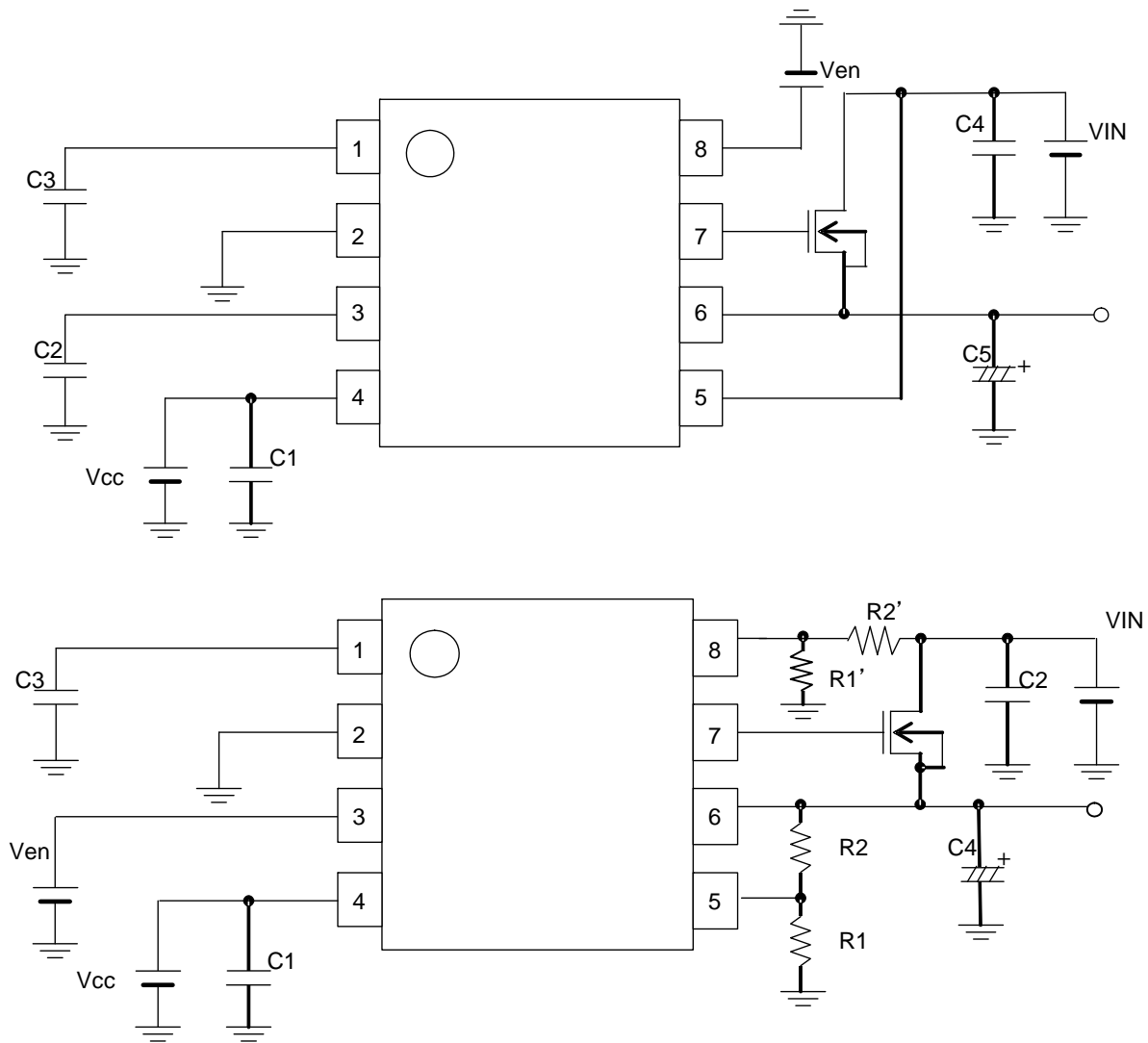
●**Directions for pattern layout of PCB**

・Because a VIN input capacitor causes impedance to drop, mount it as close to the VIN terminal as possible and use thick wiring patterns. In the event that it causes the wire to come in contact with the inner-layer ground plane, use a plurality of through holes.

・Because the NRCS terminal is analog I/O, take care to noise. In particular, high-frequency noise of GND may cause IC maloperation through capacitors. It is recommended to connect GND of NRCS capacitor to IC GND terminal at one point.

・The VFB terminal is an output voltage sense line. Effects of wiring impedance can be ignored by sensing the output voltage from the load side, but increased sense wiring causes VFB to be susceptible to noise, to which care must be taken.

・Because the GND terminal is GND to be used in analog circuit inside BD3501/02/04FVM, connect it at one point to inner-layer GND of substrate by as short pattern as possible. Arrange a bypass capacitor across VCC and GND as close as possible so that a loop can be minimized.

・The G terminal is a terminal for gate drive. If long wiring is inevitable, increase the pattern width and lower impedance.

・Heat generated in the output transistor can be calculated by:
(VIN - VOUT) × Io(Max)
Design heat generation not to exceed the guarantee temperature of transistor.

・Connect the output capacitor with thick short wiring so that the impedance is lowered. Connect capacitor GND to inner-layer GND plane by a plurality of through holes.

●Evaluation Board (BD3500/01/02FVM)
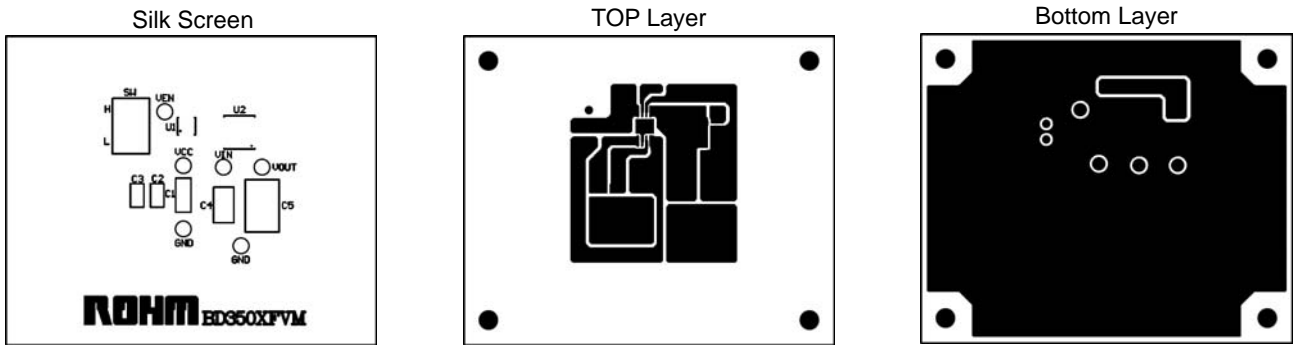
■BD350XFVM Evaluation Board Circuit
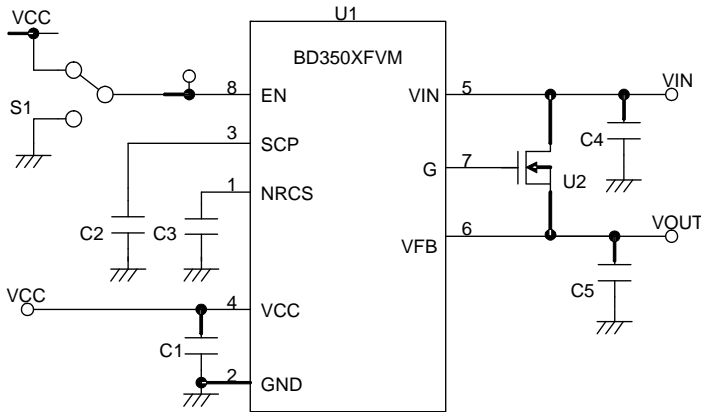
■BD350XFVM Evaluation Board Application Components

Part No	Value	Company	Parts Name
U1	-	ROHM	BD3500/01/02FVM
U2	NMOS	ROHM	RTW060N03
C1	1µF	MURATA	GRM18 series
C2	0.01µF	MURATA	GRM18 series

Part No	Value	Company	Parts Name
C3	0.01µF	MURATA	GRM18 series
C4	10µF	MURATA	GRM21 series
C5	220µF	SANYO,etc	2R5TPE220MF

■ BD350XFVM Evaluation Board Layout

Silk Screen

TOP Layer

Bottom Layer

●Evaluation Board (BD3504FVM)

■BD3504FVM Evaluation Board Circuit
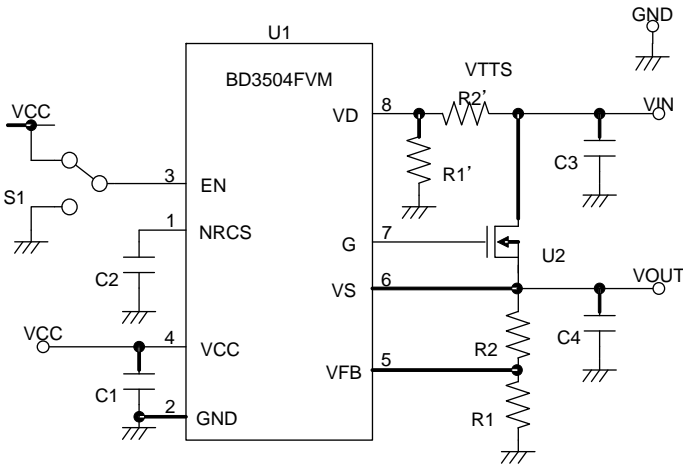
■BD3504FVM Evaluation Board Application Components

Part No	Value	Company	Parts Name
U1	-	ROHM	BD35304FVM
U2	NMOS	ROHM	RTW060N03
R1	3.9K	ROHM	MCR03EZPF3901
R1'	3.3K	ROHM	MCR03EZPF3301
R2	3.9K	ROHM	MCR03EZPF3901

Part No	Value	Company	Parts Name
R2'	3.3K	ROHM	MCR03EZPF3301
C1	1µF	MURATA	GRM18 series
C2	0.01µF	MURATA	GRM18 series
C3	10µF	MURATA	GRM21 series
C4	220µF	SANYO,etc	2R5TPE220MF

■ BD3504FVM Evaluation Board Layout

Silk Screen

TOP Layer

Bottom Layer
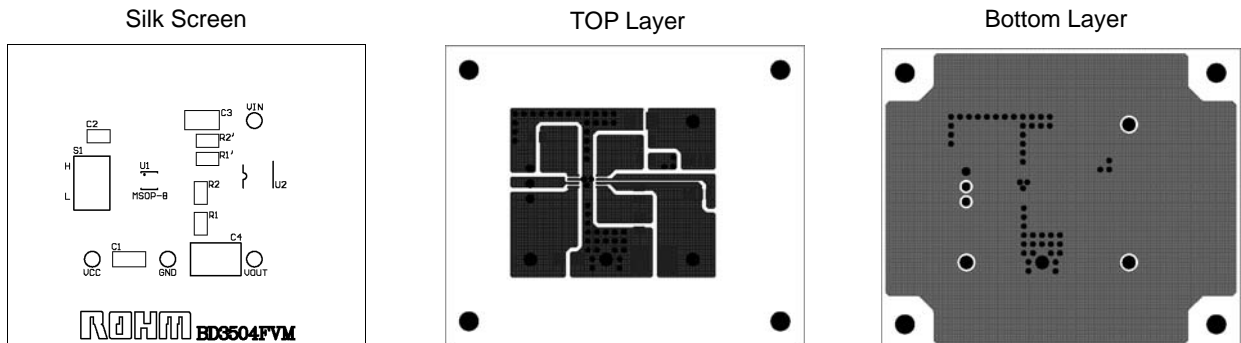
● **I/O EQUIVALENCE CIRCUIT**
◎BD3500FVM/BD3501FVM/BD3502FVM
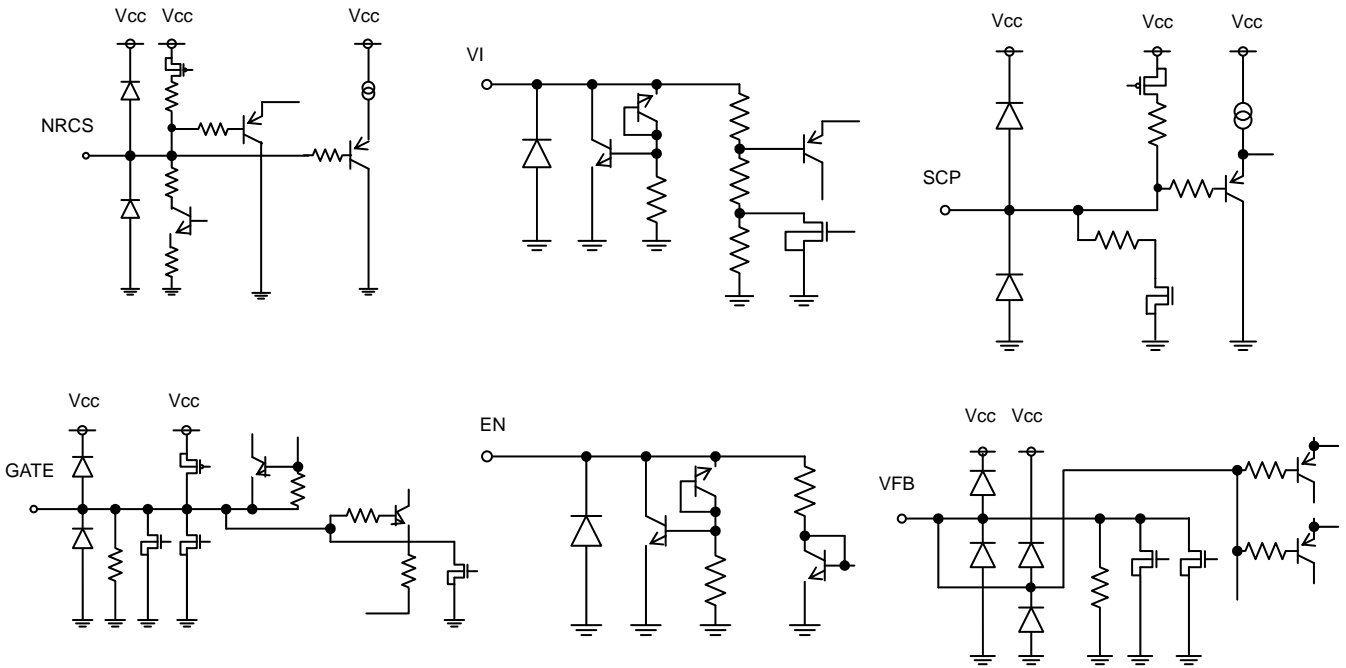
◎BD3504FVM
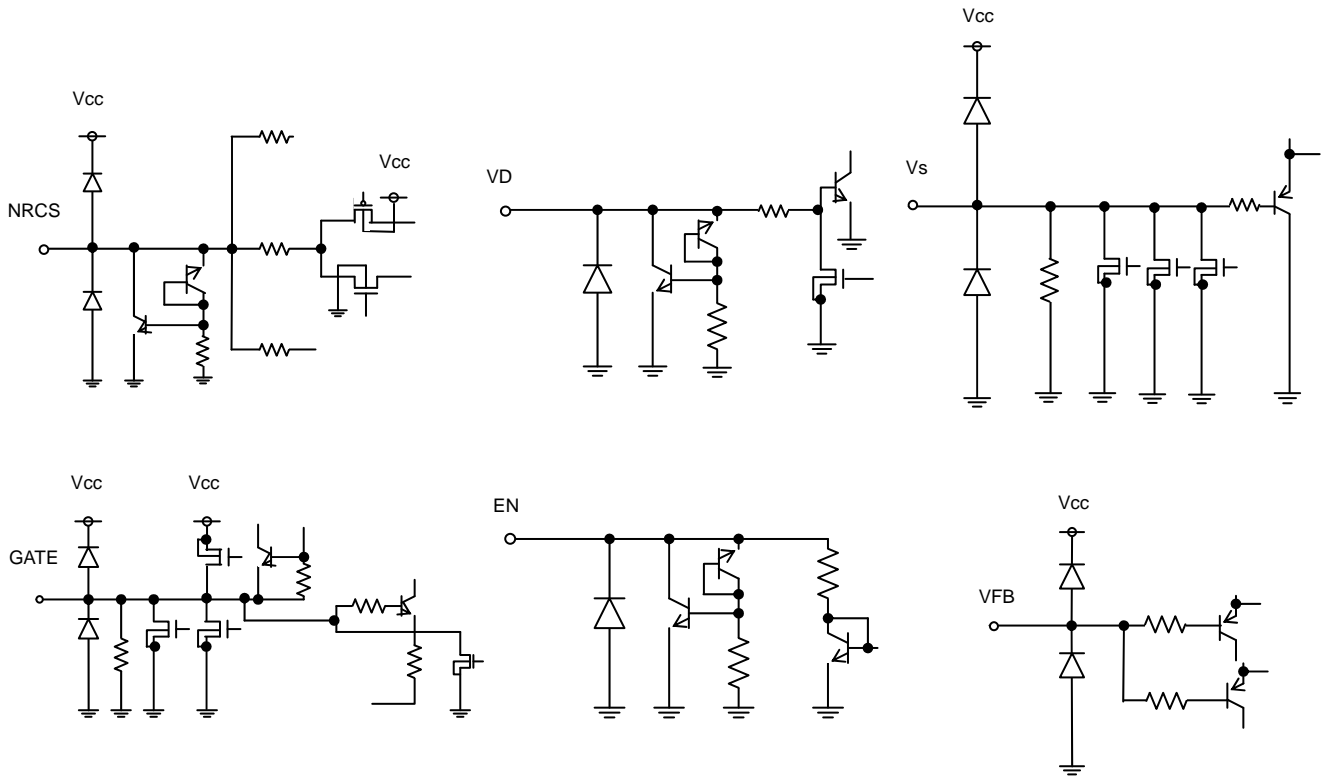
●**Notes for use**

1. Absolute maximum ratings
   For the present product, thoroughgoing quality control is carried out, but in the event that applied voltage, working temperature range, and other absolute maximum rating are exceeded, the present product may be destroyed. Because it is unable to identify the short mode, open mode, etc., if any special mode is assumed, which exceeds the absolute maximum rating, physical safety measures are requested to be taken, such as fuses, etc.

2. GND potential
   Bring the GND terminal potential to the minimum potential in any operating condition.

3. Thermal design
   Consider allowable loss (Pd) under actual working condition and carry out thermal design with sufficient margin provided.

4. Terminal-to-terminal short-circuit and erroneous mounting
   When the present IC is mounted to a printed circuit board, take utmost care to direction of IC and displacement. In the event that the IC is mounted erroneously, IC may be destroyed. In the event of short-circuit caused by foreign matter that enters in a clearance between outputs or output and power-GND, the IC may be destroyed.

5. Operation in strong electromagnetic field
   The use of the present IC in the strong electromagnetic field may result in maloperation, to which care must be taken.

6. Built-in thermal shutdown protection circuit
   The present IC incorporates a thermal shutdown protection circuit (TSD circuit). The working temperature is 175°C (standard value) and has a -15°C (standard value) hysteresis width. When the IC chip temperature rises and the TSD circuit operates, the output terminal is brought to the OFF state. The built-in thermal shutdown protection circuit (TSD circuit) is first and foremost intended for interrupt IC from thermal runaway, and is not intended to protect and warrant the IC. Consequently, never attempt to continuously use the IC after this circuit is activated or to use the circuit with the activation of the circuit premised.

7. Capacitor across output and GND
   In the event a large capacitor is connected across output and GND, when Vcc and VIN are short-circuited with 0V or GND for some kind of reasons, current charged in the capacitor flows into the output and may destroy the IC. Use a capacitor smaller than 1000 μF between output and GND.

8. Inspection by set substrate
   In the event a capacitor is connected to a pin with low impedance at the time of inspection with a set substrate, there is a fear of applying stress to the IC. Therefore, be sure to discharge electricity for every process. As electrostatic measures, provide grounding in the assembly process, and take utmost care in transportation and storage. Furthermore, when the set substrate is connected to a jig in the inspection process, be sure to turn OFF power supply to connect the jig and be sure to turn OFF power supply to remove the jig.

9. IC terminal input
   The present IC is a monolithic IC and has a P substrate and P+ isolation between elements.
   With this P layer and N layer of each element, PN junction is formed, and when the potential relation is
   - •GND>terminal A>terminal B, PN junction works as a diode, and
   - •terminal B>GND terminal A, PN junction operates as a parasitic transistor.
   The parasitic element is inevitably formed because of the IC construction. The operation of the parasitic element gives rise to mutual interference between circuits and results in malfunction, and eventually, breakdown. Consequently, take utmost care not to use the IC to operate the parasitic element such as applying voltage lower than GND (P substrate) to the input terminal.
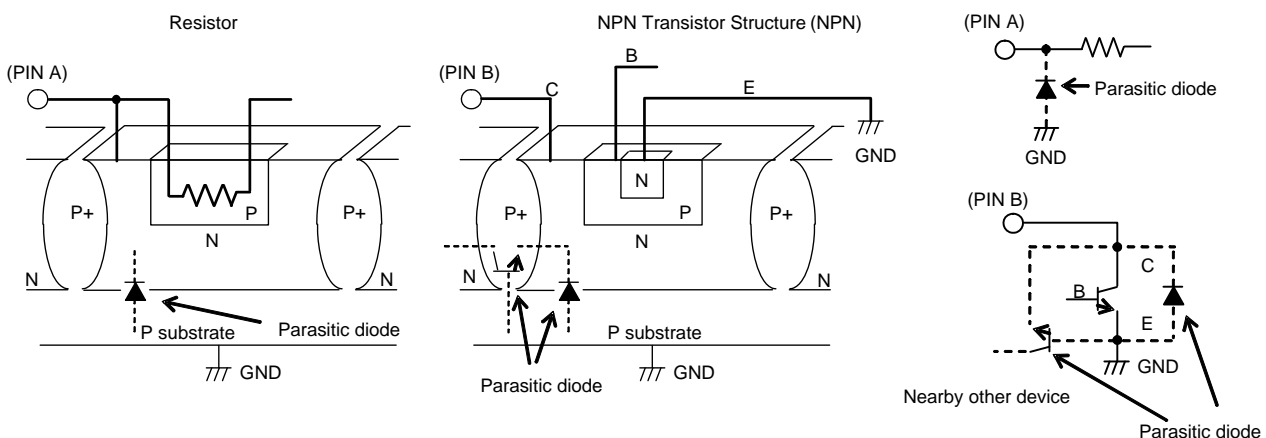
10. Output capacitor (C5)

Connect the output capacitor between Vo1, Vo2 terminals and GND terminal without fail in order to stabilize output voltage. The output capacitor has a role to compensate for the phase of loop gain and to reduce output voltage fluctuation when load is rapidly changed. When there is an insufficient capacity value, there is a possibility to cause oscillation, and when the equivalent serial resistance (ESR) of the capacitors is large, output voltage fluctuation is increased when load is rapidly changed. About 220 µF high-performance electrolytic capacitors are recommended, but this greatly depends on the gate capacity of external MOSFET and mutual conductance (gm), temperature and load conditions. In addition, when only ceramic capacitors with low ESR are used, or various capacitors are connected in series, the total phase allowance of loop gain becomes not sufficient, and oscillation may result. Thoroughgoing confirmation at application temperature and under load range conditions is requested.

11. Input capacitor setting method (C1, C4)

The input capacitor plays a part to lower output impedance of a power supply connected to input terminals (Vcc, VIN). When output impedance of this power supply increases, the input voltages (Vcc, VIN) become unstable and there is a possibility of giving rise to oscillation and degraded ripple rejection characteristics. The use of capacitors of about 10 µF with low ESR, which provide less capacity value changes caused by temperature changes, is recommended, but since input capacitor greatly depends on characteristics of the power supply used for input, substrate wiring pattern, and MOSFET gate-drain capacity, thoroughgoing confirmation under the application temperature, load range, and M-MOSFET conditions is requested.

12. NRCS terminal capacitor setting method (C3)

To the present IC, there mounted is a function (Non Rush Current on Start-up: NRCS) to prevent rush current from VIN to load and output capacitor via Vo at the output voltage start-up. When the EN terminal is reset from Hi or UVLO, constant current is allowed to flow from the NRCS terminal. By this current, voltage generated at the NRCS terminal becomes the reference voltage and output voltage is started. In order to stabilize the NRCS set time, it is recommended to use a capacitor (B special) with less capacity value change caused by temperature change.

13. SCP terminal capacitor setting method (C2)

The present IC incorporates a timer-latch type short-circuit protection circuit in order to prevent MOSFET from being destroyed by abnormal current when output terminal is short-circuited (operates at the time of NRCS, too). When the output terminal voltage drops 30% from output setting voltage, IC judges that the output is short-circuited. In such event, constant current begins to flow. When the voltage generated in the SCP terminal reaches 1.3V (Typ) by this current, the gate terminal is brought to the Low level. In order to stabilize the SCP setting time, a capacitor (B special) with less capacity value change caused by temperature changes is recommended. When the SCP function is not used, short-circuit the SCP terminal to the GND terminal. In addition, when the output terminal is short-circuited, the MOSFET gate voltage reaches the Vcc voltage and the large current that meets MOSFET characteristics flows to the output while the timer latch type protection circuit operates. When the current capacity of VIN terminal power supply lacks, the Vin terminal voltage lowers and the UVLO circuit operates, and the latch operation may not be finished. In such event, connect a limiting resistor across drain terminal and VIN terminal of MOSFET.

14. Input terminals (VCC, VIN, EN)

In the present IC, N terminal, VIN terminal, and VCC terminal have an independent construction. In addition, in order to prevent malfunction at the time of low input, the UVLO function is equipped with the VIN terminal and the VCC terminal. They begin to start output voltage when all the terminals reach threshold voltage without depending on the input order of input terminals.

15. Maximum output current (maximum load)

The maximum output current capacity of the power supply which is composed by the use of the present IC depends on the external FET. Consequently, confirm the characteristics of the power required for the set to be used, choose the external FET.

16. Operating ranges

If it is within the operating ranges, certain circuit functions and operations are warranted in the working ambient temperature range. With respect to characteristic values, it is unable to warrant standard values of electric characteristics but there are no sudden variations in characteristic values within these ranges.

17. Allowable loss Pd

With respect to the allowable loss, the thermal derating characteristics are shown in the Exhibit, which we hope would be used as a good-rule-of-thumb. Should the IC be used in such a manner to exceed the allowable loss, reduction of current capacity due to chip temperature rise, and other degraded properties inherent to the IC would result. You are strongly urged to use the IC within the allowable loss.

18. The use in the strong electromagnetic field may sometimes cause malfunction, to which care must be taken.

19. In the event that load containing a large inductance component is connected to the output terminal, and generation of back-EMF at the start-up and when output is turned OFF is assumed, it is requested to insert a protection diode.

20. We are certain that examples of applied circuit diagrams are recommendable, but you are requested to thoroughly confirm the characteristics before using the IC. In addition, when the IC is used with the external circuit changed, decide the IC with sufficient margin provided while consideration is being given not only to static characteristics but also variations of external parts and our IC including transient characteristics.

(Example)   OUTPUT PIN

●**Power Dissipation**

Without heat sink.
θ j-a=286℃/W
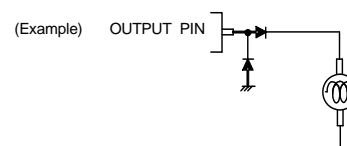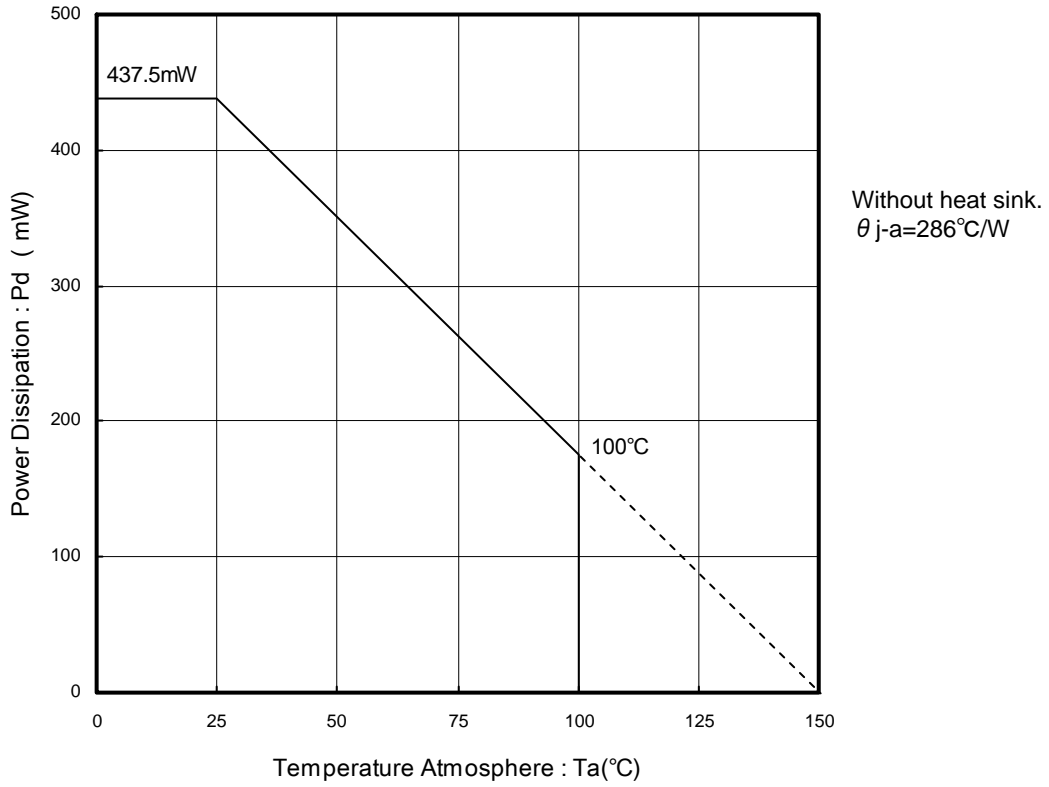
●**Ordering part number**

| B | D | | 3 | 5 | 0 | 4 | | F | V | M | - | T | R |

Part No.

Part No.
3504
3500
3501
3502

Package
FVM: MSOP8

Packaging and forming specification
TR: Embossed tape and reel
　　(MSOP8)

MSOP8

2.9±0.1
(MAX 3.25 include BURR)
4°+6°−4°
0.29±0.15
0.6±0.2
8 7 6 5
4.0±0.2
2.8±0.1
1 2 3 4
1PIN MARK
0.475
0.145 +0.05 −0.03
S
0.9MAX
0.22 +0.05 −0.04
0.75±0.05
0.08±0.05
0.65
0.08 S
(Unit : mm)

<Tape and Reel information>
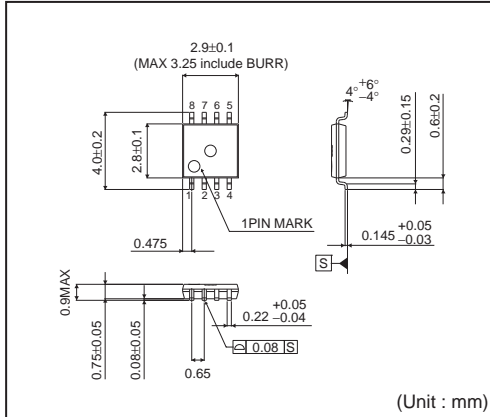
Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (The direction is the 1pin of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand)

1pin

Reel　　Direction of feed

＊Order quantity needs to be multiple of the minimum quantity.
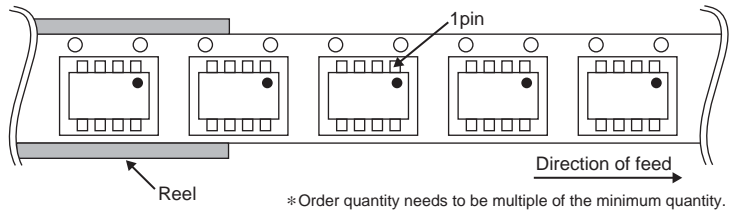
Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment [Note 1], transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSIII	CLASSIII	CLASS IIb	CLASSIII
CLASSIV		CLASSIII	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
   - [a] Installation of protection circuits or other protective devices to improve system safety
   - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
   - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
   - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   - [f] Sealing or coating our Products with resin or other coating materials
   - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   - [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
    [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
    [b] the temperature or humidity exceeds those recommended by ROHM
    [c] the Products are exposed to direct sunshine or condensation
    [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

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